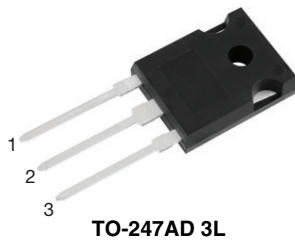
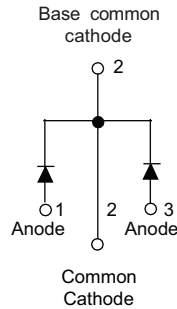


650 V Power SiC Gen 3 Merged PIN Schottky Diode, 2 x 10 A


TO-247AD 3L


FEATURES

- Majority carrier diode using Schottky technology on SiC wide band gap material
- Improved V_F and efficiency by thin wafer technology
- Positive V_F temperature coefficient, for easy paralleling
- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder Bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS COMPLIANT
 HALOGEN FREE

LINKS TO ADDITIONAL RESOURCES


[3D Models](#)

[Application Notes](#)

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
V_R	650 V
V_F at I_F at 150 °C	1.46 V
T_J max.	175 °C
I_R at V_R at 175 °C	4.5 μ A
Q_C ($V_R = 400$ V)	29 nC
Package	TO-247AD 3L
Circuit configuration	Common cathode

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise specified)				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		650	V
Average rectified forward current, per leg	$I_{F(AV)}$	$T_C = 138$ °C (DC)	10	A
DC blocking voltage	V_{DC}		650	V
Repetitive peak forward current	I_{FRM}	$T_C = 25$ °C, $f = 50$ Hz, square wave, DC = 25 %	41	A
Non-repetitive peak forward surge current, per leg	I_{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	60	
		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	58	
Power dissipation, per leg	$P_{tot}^{(1)}$	$T_C = 25$ °C	79	W
		$T_C = 110$ °C	34	
I^2t value, per leg	$\int i^2 dt$	$T_C = 25$ °C	18	A ² s
		$T_C = 110$ °C	17	
Operating junction and storage temperatures	$T_J^{(2)}, T_{Stg}$		-55 to +175	°C

Notes

(1) Based on maximum R_{th}

(2) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{thJA}$



ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Forward voltage, per leg	V_F	$I_F = 10\text{ A}$	-	1.3	1.5	V
		$I_F = 10\text{ A}, T_J = 150\text{ }^\circ\text{C}$	-	1.46	1.85	
		$I_F = 10\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	1.52	-	
Reverse leakage current, per leg	I_R	$V_R = V_R\text{ rated}$	-	0.7	55	μA
		$V_R = V_R\text{ rated}, T_J = 150\text{ }^\circ\text{C}$	-	2.8	125	
		$V_R = V_R\text{ rated}, T_J = 175\text{ }^\circ\text{C}$	-	4.5	-	
Total capacitance, per leg	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	445	-	pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	43	-	
Total capacitive charge, per leg	Q_C	$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	29	-	nC

THERMAL - MECHANICAL SPECIFICATIONS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	per leg	R_{thJC}		-	1.4	1.9	$^\circ\text{C/W}$
	per device			-	0.8	1	$^\circ\text{C/W}$
Marking device				3C20CP07L			

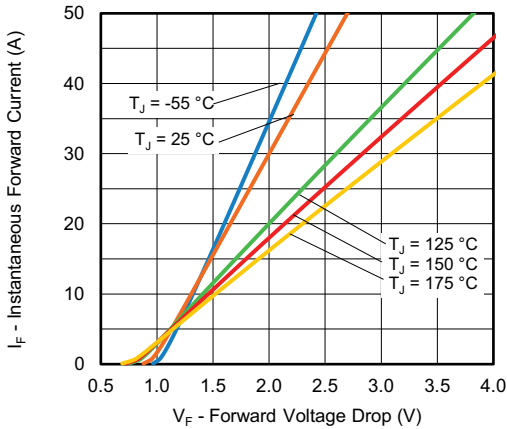


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Leg

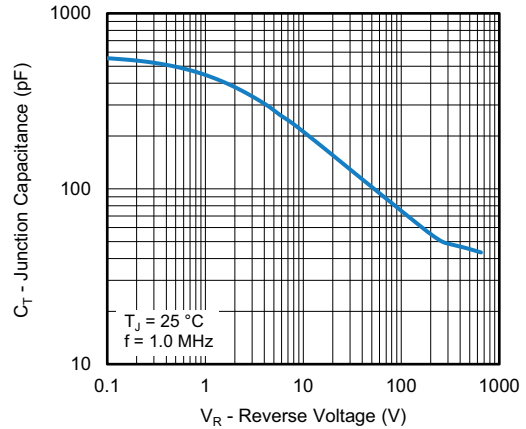


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

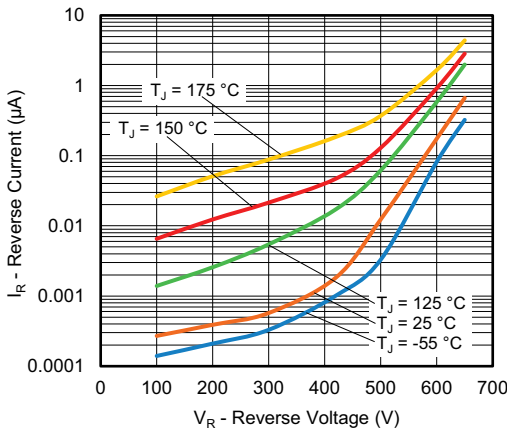


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

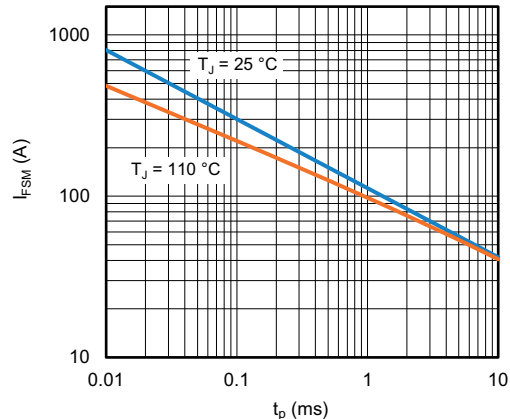


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration, Per Leg (Square Wave)

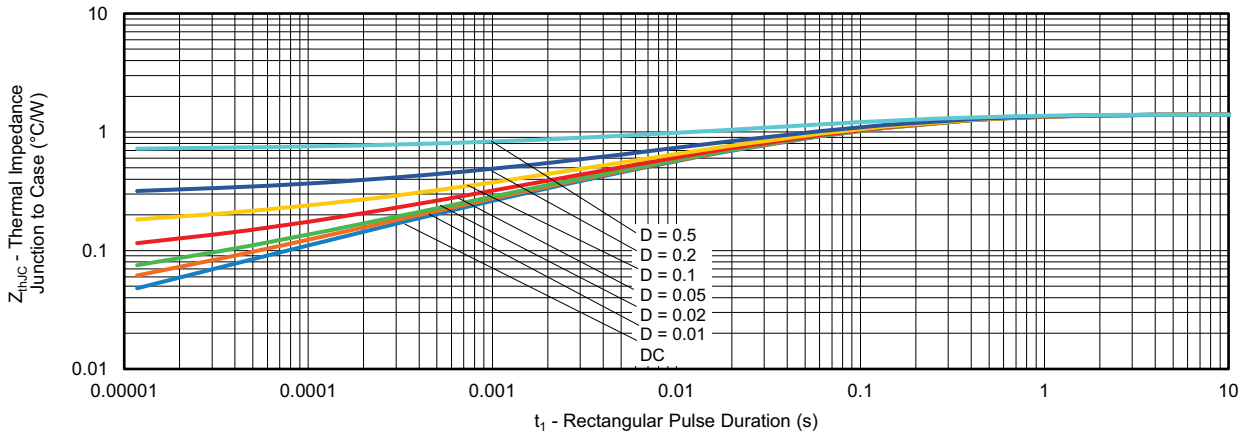


Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics, Per Leg

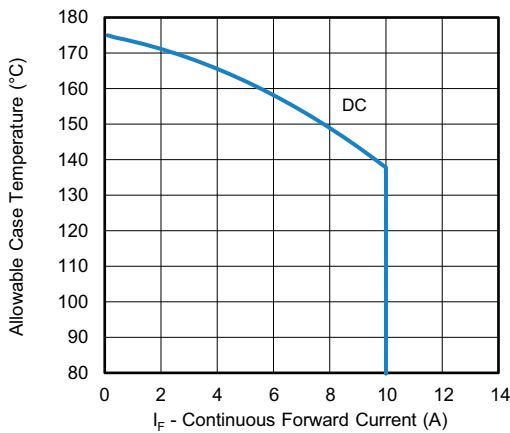


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

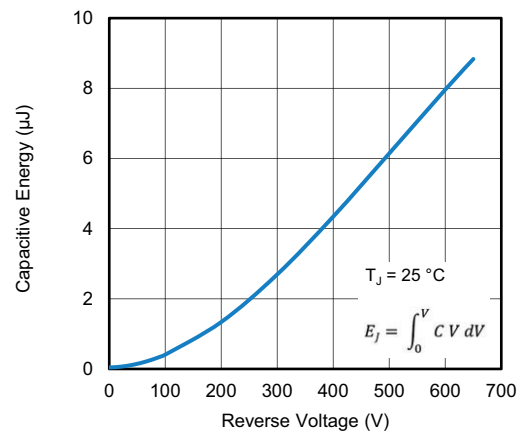


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage, Per Leg

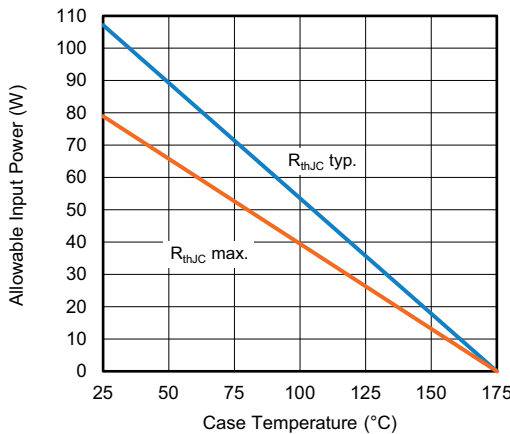


Fig. 7 - Forward Power Loss Characteristics, Per Leg

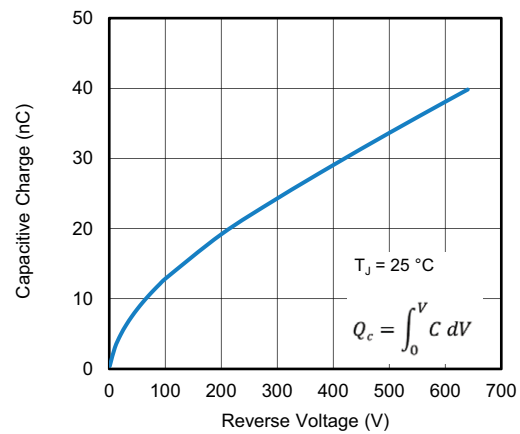
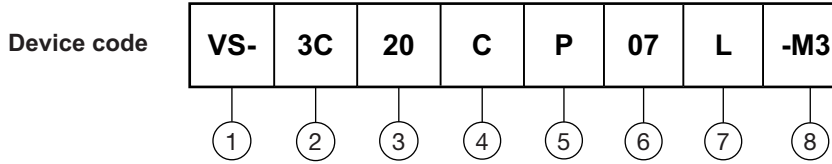


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage, Per Leg



ORDERING INFORMATION TABLE



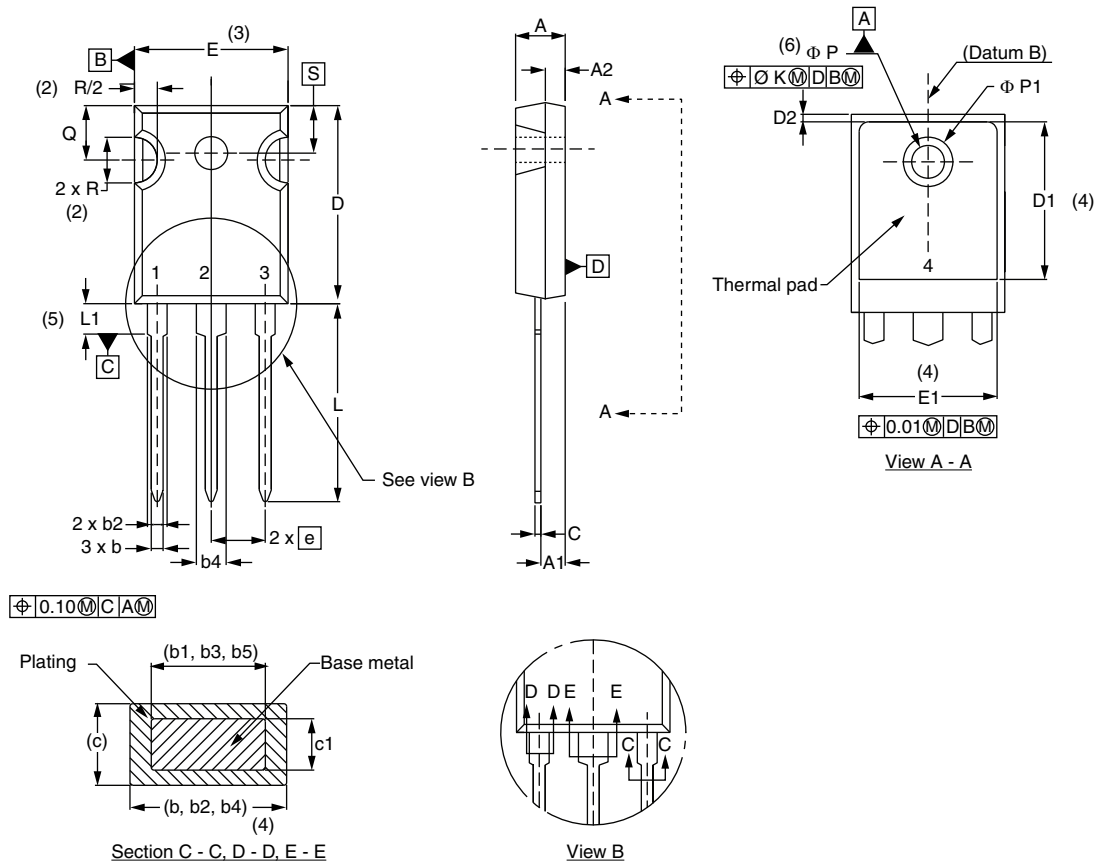
- 1** - Vishay Semiconductors product
- 2** - 3C = SiC diode, Generation 3
- 3** - Current rating (20 = 20 A)
- 4** - C = common cathode
- 5** - P = package TO-247
- 6** - Voltage rating: (07 = 650 V)
- 7** - L = long lead
- 8** - Environmental digit:
-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-3C20CP07L-M3	25/tube	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95626
Part marking information	www.vishay.com/doc?95007

TO-247AD 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209		D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098		E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055		e	5.46 BSC		0.215 BSC		
b1	0.99	1.35	0.039	0.053		Ø K	0.254		0.010		
b2	1.65	2.39	0.065	0.094		L	19.81	20.32	0.780	0.800	
b3	1.65	2.34	0.065	0.092		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		Ø P	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133		Ø P1	-	6.98	-	0.275	
c	0.38	0.89	0.015	0.035		Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033		R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3	S	5.51 BSC		0.217 BSC		
D1	13.08	-	0.515	-	4						

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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